

FEATURES

- Ultralow noise: 9 $\mu\text{V rms}$**
- No noise bypass capacitor required**
- Stable with 1 μF ceramic input and output capacitors**
- Maximum output current: 200 mA**
- Input voltage range: 2.2 V to 5.5 V**
- Low quiescent current**
 - $I_{\text{GND}} = 10 \mu\text{A}$ with $I_{\text{OUT}} = 0 \mu\text{A}$
 - $I_{\text{GND}} = 265 \mu\text{A}$ with $I_{\text{OUT}} = 200 \text{ mA}$
- Low shutdown current: $<1 \mu\text{A}$**
- Low dropout voltage: 135 mV at $I_{\text{OUT}} = 200 \text{ mA}$**
- Initial accuracy: $\pm 1\%$**
- Accuracy over line, load, and temperature: $\pm 2.5\%$**
- 16 fixed output voltage options: 1.1 V to 3.3 V**
- PSRR performance of 70 dB at 10 kHz**
- Current-limit and thermal overload protection**
- Logic controlled enable**
- Internal pull-down resistor on EN input**
- 5-lead TSOT package**
- 6-lead LFCSP package**
- 4-ball, 0.4 mm pitch WLCSP**
- AEC-Q100 qualified for automotive applications**

APPLICATIONS

- RF, voltage controlled oscillator (VCO), and phase locked loop (PLL) power supplies**
- Mobile phones**
- Digital camera and audio devices**
- Portable and battery-powered equipment**
- Post dc-to-dc regulation**
- Portable medical devices**

GENERAL DESCRIPTION

The ADP151 is an ultralow noise, low dropout (LDO) linear regulator that operates from 2.2 V to 5.5 V and provides up to 200 mA of output current. The low 135 mV dropout voltage at 200 mA load improves efficiency and allows operation over a wide input voltage range.

Using an innovative circuit topology, the ADP151 achieves ultralow noise performance without the necessity of a bypass capacitor, making the device ideal for noise sensitive analog and RF applications. The ADP151 also achieves ultralow noise performance without compromising the power supply rejection ratio (PSRR) or transient line and load performance. The low 265 μA of operating supply current at 200 mA load makes the ADP151 suitable for battery-operated portable equipment.

Rev. I

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TYPICAL APPLICATION CIRCUITS

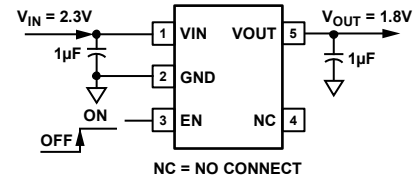


Figure 1. TSOT ADP151 with Fixed Output Voltage, 1.8 V

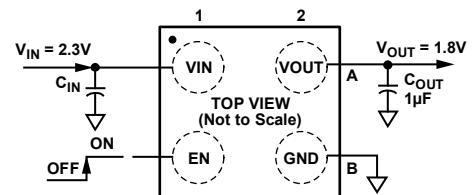


Figure 2. WLCSP ADP151 with Fixed Output Voltage, 1.8 V

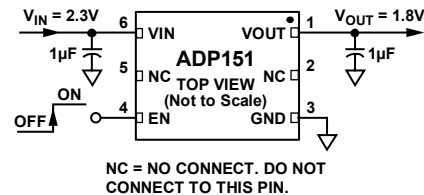


Figure 3. LFCSP ADP151 with Fixed Output Voltage, 1.8 V

The ADP151 also includes an internal pull-down resistor on the EN input.

The ADP151 is specifically designed for stable operation with tiny 1 μF , $\pm 30\%$ ceramic input and output capacitors to meet the requirements of high performance, space constrained applications.

The ADP151 is capable of 16 fixed output voltage options, ranging from 1.1 V to 3.3 V.

Short-circuit and thermal overload protection circuits prevent damage in adverse conditions. The ADP151 is available in tiny 5-lead TSOT, 6-lead LFCSP, and 4-ball, 0.4 mm pitch, halide-free WLCSP packages for the smallest footprint solution to meet a variety of portable power application requirements.

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REVISION HISTORY

9/2020—Rev. H to Rev. I

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1/2020—Rev. G to Rev. H

Changes to Features Section	1
Added Current-Limit Threshold, W Grade Parameter, Table 1 and Input Voltage Rising, W Grade Parameter, Table 1	4
Changes to Ordering Guide.....	22
Added Automotive Products Section	23

12/2019—Rev. F to Rev. G

Changes to Features Section	1
Deleted Input Voltage Rising, W Grade Parameter, Table 1	4
Changes to Ordering Guide.....	22
Deleted Automotive Products Section	23

12/2019—Rev. E to Rev. F

Changes to Features Section and General Description Section	1
Added Input Voltage Rising, W Grade Parameter, Table 1.....	4
Changes to Ordering Guide.....	22
Added Automotive Products Section	23

4/2012—Rev. D to Rev. E

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Updated Outline Dimensions.....	21
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3/2011—Rev. C to Rev. D

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1/2011—Rev. B to Rev. C

Changes to Figure 23	9
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12/2010—Rev. A to Rev. B

Added LFCSP Package	Universal
Added Figure 3; Renumbered Sequentially	1
Added Table 2 Caption; Renumbered Sequentially	4
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8/2010—Rev. 0 to Rev. A

Changes to Figure 8	7
Changes to Figure 15 Caption and Figure 16 Caption	8
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3/2010—Revision 0: Initial Version

SPECIFICATIONS

$V_{IN} = (V_{OUT} + 0.4 \text{ V})$ or 2.2 V, whichever is greater, $EN = V_{IN}$, $I_{OUT} = 10 \text{ mA}$, $C_{IN} = C_{OUT} = 1 \mu\text{F}$, and $T_A = 25^\circ\text{C}$, unless otherwise noted. Note that V_{IN} is the input voltage, V_{OUT} is the output voltage, I_{OUT} is the output current, C_{IN} is the input capacitance, and C_{OUT} is the output capacitance.

Table 1.

Parameter	Symbol	Test Conditions/Conditions	Min	Typ	Max	Unit
INPUT VOLTAGE RANGE	V_{IN}	$T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$	2.2		5.5	V
OPERATING SUPPLY CURRENT	I_{GND}	$I_{OUT} = 0 \mu\text{A}$ $I_{OUT} = 0 \mu\text{A}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ $I_{OUT} = 100 \mu\text{A}$ $I_{OUT} = 100 \mu\text{A}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ $I_{OUT} = 10 \text{ mA}$ $I_{OUT} = 10 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ $I_{OUT} = 200 \text{ mA}$ $I_{OUT} = 200 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$		10	20	μA μA μA μA μA μA μA
SHUTDOWN CURRENT	I_{GND-SD}	$EN = GND$ $EN = GND$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$		0.2	1.0	μA μA
OUTPUT VOLTAGE ACCURACY	V_{OUT}					
TSOT/LFCSP		$I_{OUT} = 10 \text{ mA}$ $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{OUT} < 1.8 \text{ V}$	-1		+1	%
		$100 \mu\text{A} < I_{OUT} < 200 \text{ mA}$, $V_{IN} = (V_{OUT} + 0.4 \text{ V})$ to 5.5 V $V_{OUT} \geq 1.8 \text{ V}$	-3		+2	%
WLCSP		$100 \mu\text{A} < I_{OUT} < 200 \text{ mA}$, $V_{IN} = (V_{OUT} + 0.4 \text{ V})$ to 5.5 V $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{OUT} < 1.8 \text{ V}$	-2.5		+1.5	%
		$100 \mu\text{A} < I_{OUT} < 200 \text{ mA}$, $V_{IN} = (V_{OUT} + 0.4 \text{ V})$ to 5.5 V $V_{OUT} \geq 1.8 \text{ V}$	-2.5		+2	%
		$100 \mu\text{A} < I_{OUT} < 200 \text{ mA}$, $V_{IN} = (V_{OUT} + 0.4 \text{ V})$ to 5.5 V	-2		+1.5	%
REGULATION						
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$V_{IN} = (V_{OUT} + 0.4 \text{ V})$ to 5.5 V, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$	-0.05		+0.05	%/V
Load Regulation (TSOT/LFCSP) ¹	$\Delta V_{OUT}/\Delta I_{OUT}$	$V_{OUT} < 1.8 \text{ V}$ $I_{OUT} = 100 \mu\text{A}$ to 200 mA		0.006		%/mA %/mA
		$I_{OUT} = 100 \mu\text{A}$ to 200 mA, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{OUT} \geq 1.8 \text{ V}$			0.012	%/mA
Load Regulation (WLCSP) ¹	$\Delta V_{OUT}/\Delta I_{OUT}$	$I_{OUT} = 100 \mu\text{A}$ to 200 mA $I_{OUT} = 100 \mu\text{A}$ to 200 mA, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$		0.003	0.008	%/mA %/mA
		$V_{OUT} < 1.8 \text{ V}$ $I_{OUT} = 100 \mu\text{A}$ to 200 mA		0.004		%/mA
		$I_{OUT} = 100 \mu\text{A}$ to 200 mA, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{OUT} \geq 1.8 \text{ V}$			0.009	%/mA
		$I_{OUT} = 100 \mu\text{A}$ to 200 mA		0.002		%/mA
		$I_{OUT} = 100 \mu\text{A}$ to 200 mA, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$			0.006	%/mA
DROPOUT VOLTAGE ²	$V_{DROPOUT}$					
		$I_{OUT} = 10 \text{ mA}$		10		mV
TSOT/LFCSP		$I_{OUT} = 10 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$ $I_{OUT} = 200 \text{ mA}$			30	mV mV
		$I_{OUT} = 200 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$		150		mV
WLCSP		$I_{OUT} = 200 \text{ mA}$			230	mV
		$I_{OUT} = 200 \text{ mA}$ $I_{OUT} = 200 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$		135		mV mV
		$I_{OUT} = 200 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$			200	mV

Parameter	Symbol	Test Conditions/Conditions	Min	Typ	Max	Unit
START-UP TIME ³	$t_{\text{START-UP}}$	$V_{\text{OUT}} = 3.3 \text{ V}$		180		μs
CURRENT-LIMIT THRESHOLD ⁴	I_{LIMIT}	$T_J = 0^\circ\text{C to } +125^\circ\text{C}$ W grade, $T_J = -40^\circ\text{C to } +125^\circ\text{C}$	220 205	300 300	400 400	mA mA
UNDERVOLTAGE LOCKOUT Input Voltage Rising	$UVLO_{\text{RISE}}$	$T_J = -40^\circ\text{C to } +125^\circ\text{C}$ W grade			1.96	V
Input Voltage Falling	$UVLO_{\text{FALL}}$		1.28		1.86	V
Hysteresis	$UVLO_{\text{HYS}}$			120		mV
THERMAL SHUTDOWN Thermal Shutdown Threshold	TS_{SD}	T_J rising		150		$^\circ\text{C}$
Thermal Shutdown Hysteresis	$TS_{\text{SD-HYS}}$			15		$^\circ\text{C}$
EN INPUT EN Input Logic High	V_{IH}	$2.2 \text{ V} \leq V_{\text{IN}} \leq 5.5 \text{ V}$ $2.2 \text{ V} \leq V_{\text{IN}} \leq 5.5 \text{ V}$ $V_{\text{IN}} = \text{EN voltage } (V_{\text{EN}}) = 5.5 \text{ V}$	1.2			V
EN Input Logic Low	V_{IL}				0.4	V
EN Input Pull-Down Resistance	R_{EN}				2.6	$\text{M}\Omega$
OUTPUT NOISE	OUT_{NOISE}	10 Hz to 100 kHz, $V_{\text{IN}} = 5 \text{ V}$, $V_{\text{OUT}} = 3.3 \text{ V}$		9		$\mu\text{V rms}$
		10 Hz to 100 kHz, $V_{\text{IN}} = 5 \text{ V}$, $V_{\text{OUT}} = 2.5 \text{ V}$		9		$\mu\text{V rms}$
		10 Hz to 100 kHz, $V_{\text{IN}} = 5 \text{ V}$, $V_{\text{OUT}} = 1.1 \text{ V}$		9		$\mu\text{V rms}$
POWER SUPPLY REJECTION RATIO $V_{\text{IN}} = V_{\text{OUT}} + 0.5 \text{ V}$	PSRR	10 kHz, $V_{\text{IN}} = 3.8 \text{ V}$, $V_{\text{OUT}} = 3.3 \text{ V}$, $I_{\text{OUT}} = 10 \text{ mA}$		70		dB
		100 kHz, $V_{\text{IN}} = 3.8 \text{ V}$, $V_{\text{OUT}} = 3.3 \text{ V}$, $I_{\text{OUT}} = 10 \text{ mA}$		55		dB
		10 kHz, $V_{\text{IN}} = 4.3 \text{ V}$, $V_{\text{OUT}} = 3.3 \text{ V}$, $I_{\text{OUT}} = 10 \text{ mA}$		70		dB
		100 kHz, $V_{\text{IN}} = 4.3 \text{ V}$, $V_{\text{OUT}} = 3.3 \text{ V}$, $I_{\text{OUT}} = 10 \text{ mA}$		55		dB
		10 kHz, $V_{\text{IN}} = 2.2 \text{ V}$, $V_{\text{OUT}} = 1.1 \text{ V}$, $I_{\text{OUT}} = 10 \text{ mA}$		70		dB
$V_{\text{IN}} = V_{\text{OUT}} + 1 \text{ V}$		100 kHz, $V_{\text{IN}} = 2.2 \text{ V}$, $V_{\text{OUT}} = 1.1 \text{ V}$, $I_{\text{OUT}} = 10 \text{ mA}$		55		dB

¹ Based on an end-point calculation using 0.1 mA and 200 mA loads. See Figure 8 for typical load regulation performance for loads less than 1 mA.

² Dropout voltage is defined as the input-to-output voltage differential when the input voltage is set to the nominal output voltage. This voltage applies only for output voltages above 2.2 V.

³ Start-up time is defined as the time between the rising edge of EN and V_{OUT} being at 90% of its nominal value.

⁴ Current-limit threshold is defined as the current at which the output voltage drops to 90% of the specified typical value. For example, the current limit for a 3.0 V output voltage is defined as the current that causes the output voltage to drop to 90% of 3.0 V (that is, 2.7 V).

INPUT AND OUTPUT CAPACITOR, RECOMMENDED SPECIFICATIONS

Table 2.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
Minimum Input and Output Capacitance ¹	C_{MIN}	$T_A = -40^\circ\text{C to } +125^\circ\text{C}$	0.7			μF
Capacitor ESR	R_{ESR}	$T_A = -40^\circ\text{C to } +125^\circ\text{C}$	0.001		0.2	Ω

¹ The minimum input and output capacitance must be greater than 0.7 μF over the full range of operating conditions. The full range of operating conditions in the application must be considered during device selection to ensure that the minimum capacitance specification is met. X7R and X5R type capacitors are recommended, and Y5V and Z5U capacitors are not recommended for use with any low dropout (LDO) regulator.

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
VIN to GND	–0.3 V to +6.5 V
VOU to GND	–0.3 V to VIN
EN to GND	–0.3 V to +6.5 V
Temperature Range	
Storage	–65°C to +150°C
Operating Junction	–40°C to +125°C
Operating Ambient	–40°C to +125°C
Soldering Conditions	JEDEC J-STD-020

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL DATA

Absolute maximum ratings apply individually only, not in combination. The ADP151 can be damaged when the junction temperature limits are exceeded. Monitoring ambient temperature does not guarantee that T_J is within the specified temperature limits. In applications with high power dissipation and poor thermal resistance, the maximum ambient temperature may have to be derated.

In applications with moderate power dissipation and low printed circuit board (PCB) thermal resistance, the maximum ambient temperature can exceed the maximum limit as long as the junction temperature is within specification limits. T_J of the device is dependent on T_A , the power dissipation of the device (P_D), and the junction to ambient thermal resistance of the package (θ_{JA}).

To calculate the maximum T_J from T_A and P_D use the following equation:

$$T_J = T_A + (P_D \times \theta_{JA})$$

The θ_{JA} of the package is based on modeling and calculation using a 4-layer board. θ_{JA} is highly dependent on the application and board layout. In applications where high maximum P_D exists, close attention to thermal board design is required. The value of θ_{JA} may vary, depending on PCB material, layout, and environmental conditions. The specified values of θ_{JA} are based on a 4-layer, 4 inches \times 3 inches circuit board. See JESD51-7 and JESD51-9 for detailed information on the board construction. For additional information, see the [AN-617 Application Note](#), *MicroCSP™ Wafer Level Chip Scale Package*.

Ψ_{JB} is the junction to board, thermal characterization parameter with units of °C/W. Ψ_{JB} of the package is based on modeling and calculation using a 4-layer board. The JESD51-12, *Guidelines for Reporting and Using Electronic Package Thermal Information*, states that thermal characterization parameters are not the same as thermal resistances. Ψ_{JB} measures the component power flowing through multiple thermal paths rather than a single path as in θ_{JB} . Therefore, Ψ_{JB} thermal paths include convection from the top of the package as well as radiation from the package, factors that make Ψ_{JB} more useful in real-world applications. To calculate the maximum T_J from the board temperature (T_B) and P_D , use the following equation:

$$T_J = T_B + (P_D \times \Psi_{JB})$$

See JESD51-8 and JESD51-12 for more detailed information about Ψ_{JB} .

THERMAL RESISTANCE

θ_{JA} and Ψ_{JB} are specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 4. Thermal Resistance

Package Type	θ_{JA}	Ψ_{JB}	Unit
5-Lead TSOT (UJ-5)	170	43	°C/W
4-Ball WLCSP (CB-4-3)	260	58	°C/W
6-Lead LFCSP (CP-6-3)	63.6	28.3	°C/W

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

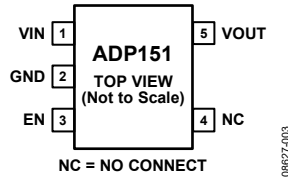
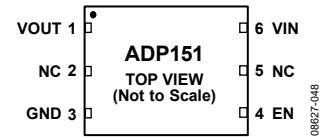


Figure 4. 5-Lead TSOT Pin Configuration



NOTES
 1. NC = NO CONNECT. DO NOT CONNECT TO THIS PIN.
 2. THE EXPOSED PAD MUST BE CONNECTED TO GROUND.

Figure 6. 6-Lead LFCSP Pin Configuration

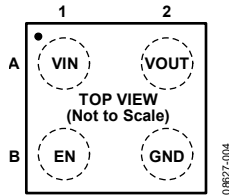


Figure 5. 4-Ball WLCSP Ball Configuration

Table 5. Pin Function Descriptions

Pin No.			Mnemonic	Description
TSOT	WLCSP	LFCSP		
1	A1	6	VIN	Regulator Input Supply. Bypass VIN to GND with a 1 μ F or greater capacitor.
2	B2	3	GND	Ground.
3	B1	4	EN	Enable Input. Drive EN high to turn on the regulator and drive EN low to turn off the regulator. For automatic startup, connect EN to VIN.
4	Not applicable	2	NC	No Connect. Not connected internally.
5	A2	1	VOUT	Regulated Output Voltage. Bypass VOUT to GND with a 1 μ F or greater capacitor.
Not applicable	Not applicable	5	NC	No Connect. Not connected internally.
Not applicable	Not applicable		EPAD	Exposed Pad. The exposed pad must be connected to ground. The exposed pad enhances the thermal performance of the package.

TYPICAL PERFORMANCE CHARACTERISTICS

$V_{IN} = 5\text{ V}$, $V_{OUT} = 3.3\text{ V}$, $I_{OUT} = 1\text{ mA}$, $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$, and $T_A = 25^\circ\text{C}$, unless otherwise noted.

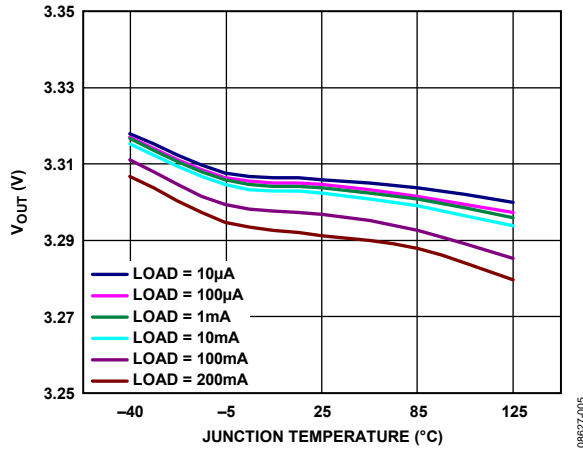


Figure 7. V_{OUT} vs. Junction Temperature

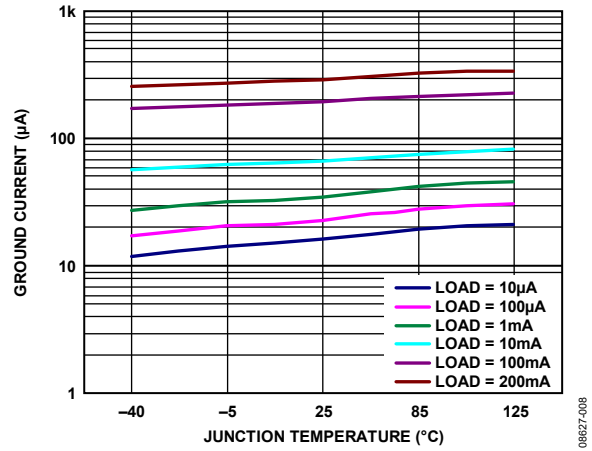


Figure 10. Ground Current vs. Junction Temperature

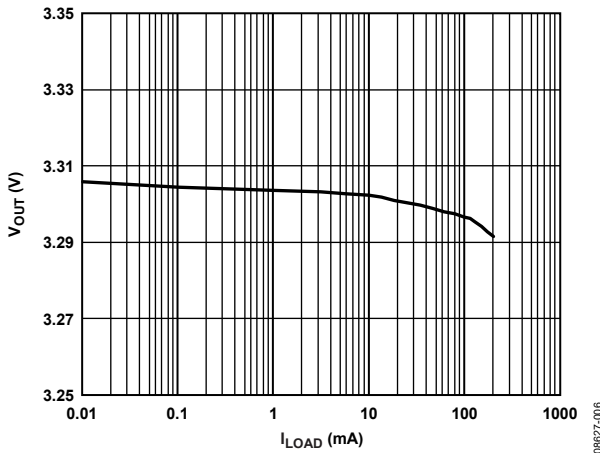


Figure 8. V_{OUT} vs. Load Current (I_{LOAD})

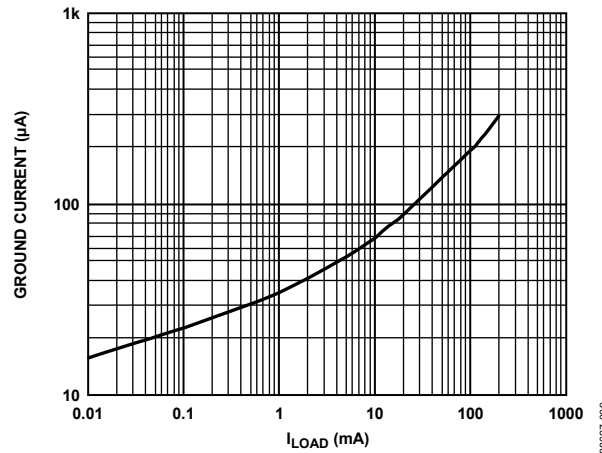


Figure 11. Ground Current vs. I_{LOAD}

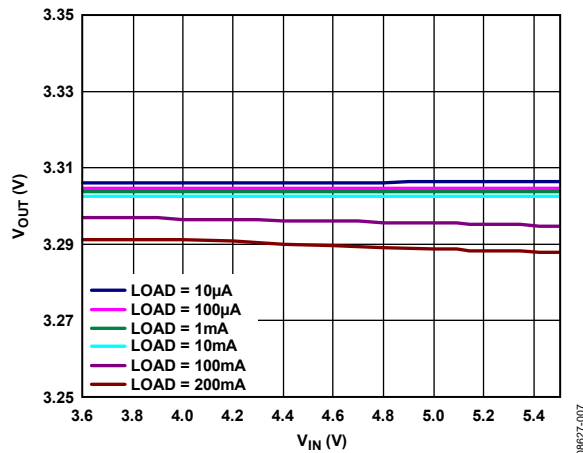


Figure 9. V_{OUT} vs. V_{IN}

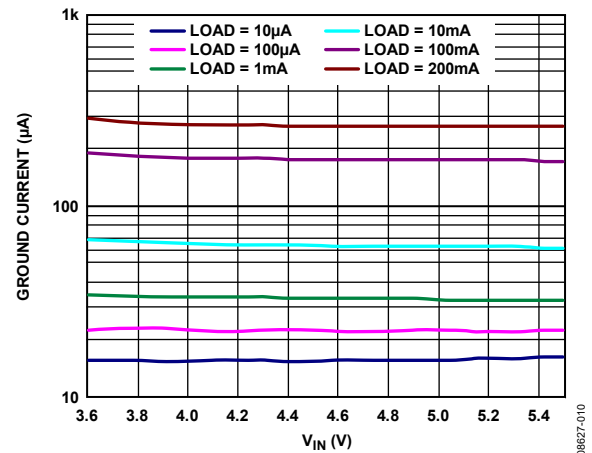


Figure 12. Ground Current vs. V_{IN}

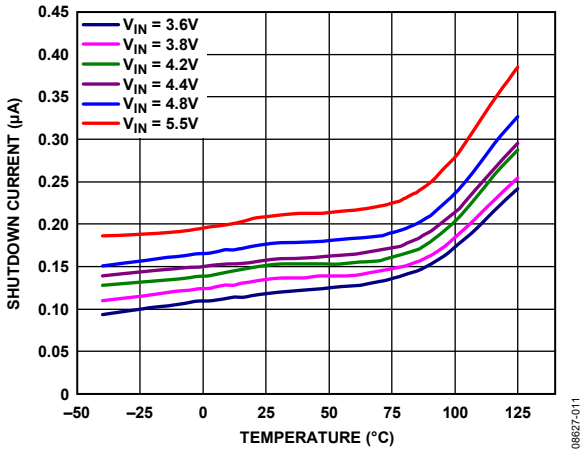


Figure 13. Shutdown Current vs. Temperature at Various Input Voltages

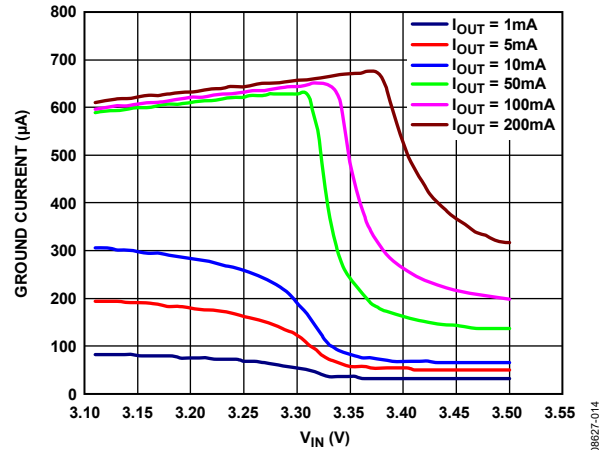


Figure 16. Ground Current vs. VIN (in Dropout)

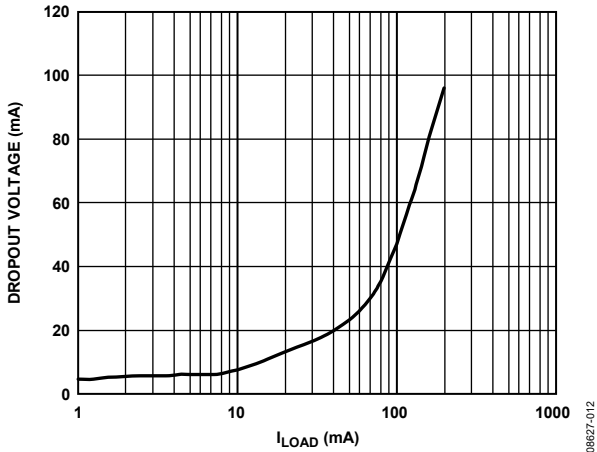


Figure 14. Dropout Voltage vs. ILOAD

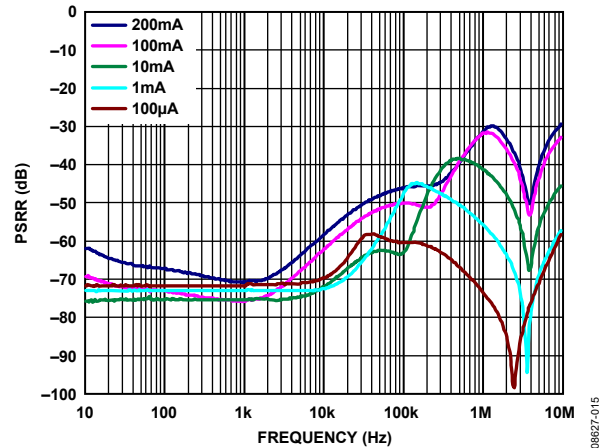


Figure 17. PSRR vs. Frequency, VOUT = 1.2 V, VIN = 2.2 V

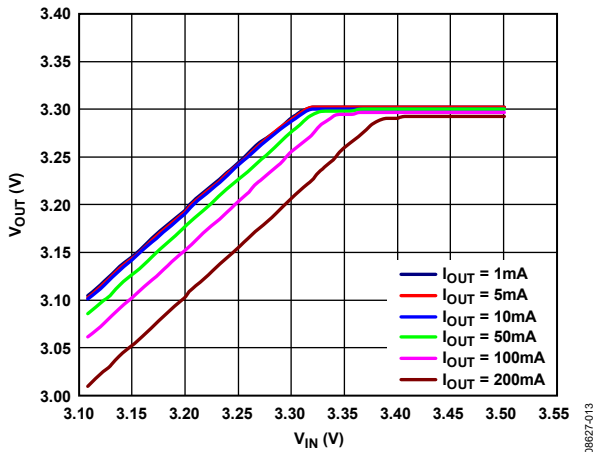


Figure 15. VOUT vs. VIN (in Dropout)

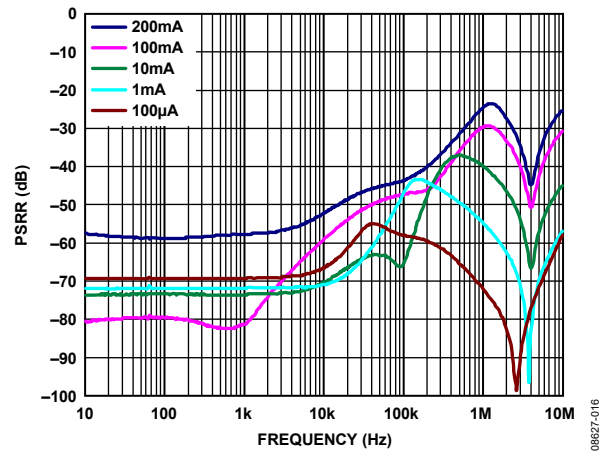


Figure 18. PSRR vs. Frequency, VOUT = 2.8 V, VIN = 3.3 V

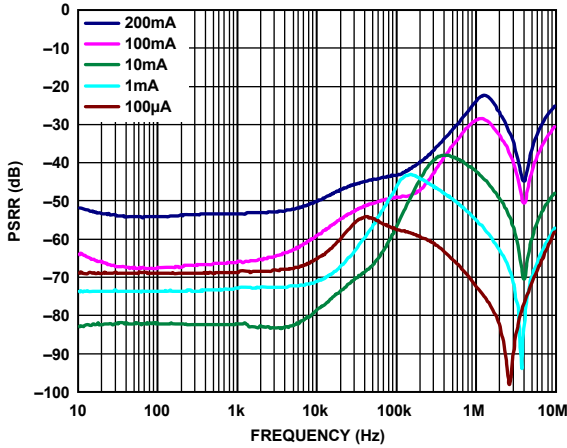


Figure 19. PSRR vs. Frequency, $V_{OUT} = 3.3V$, $V_{IN} = 3.8V$

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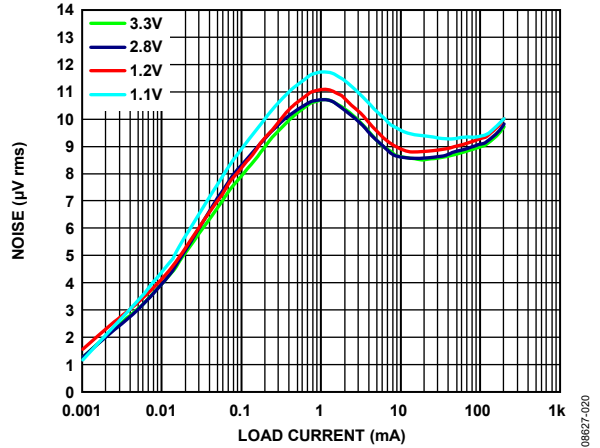


Figure 22. Output Noise vs. Load Current for Various Output Voltages, $V_{IN} = 5V$, $C_{OUT} = 1\mu F$

08627-020

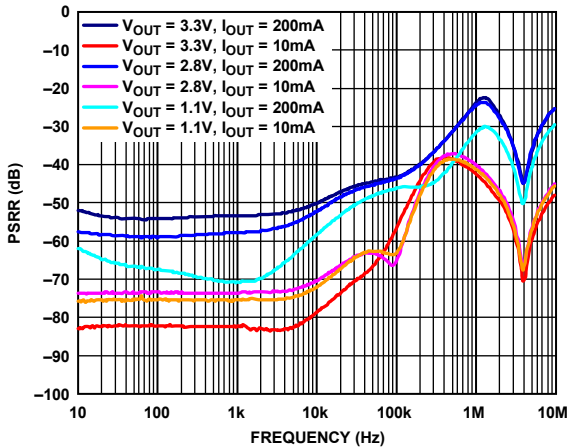


Figure 20. PSRR vs. Frequency at Various Output Voltages and Load Currents, $V_{OUT} - V_{IN} = 0.5V$, Except for $V_{OUT} = 1.1V$, $V_{IN} = 2.2V$

08627-018

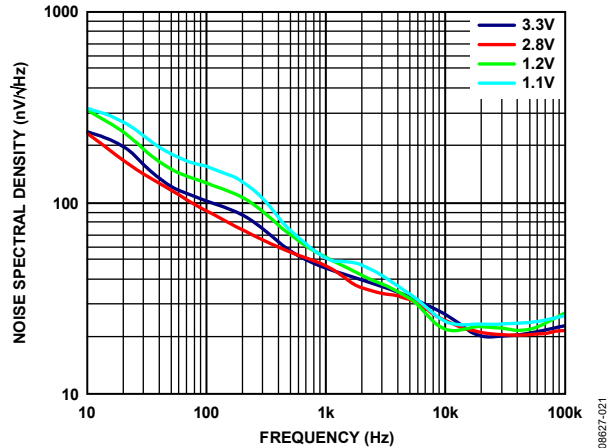


Figure 23. Output Noise Spectral Density vs. Frequency, $V_{IN} = 5V$, $I_{LOAD} = 10mA$, $C_{OUT} = 1\mu F$

08627-021

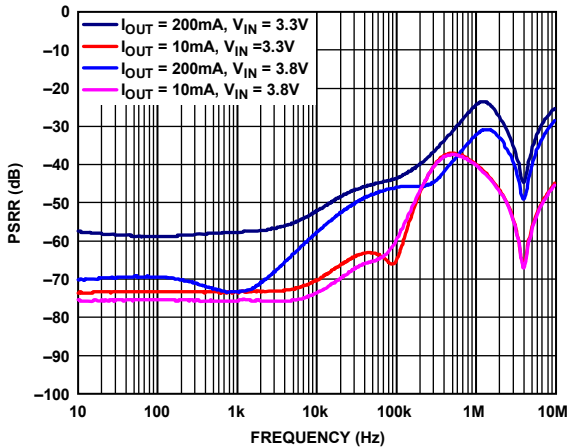


Figure 21. PSRR vs. Frequency at Various Voltages and Load Currents, $V_{OUT} = 2.8V$

08627-019

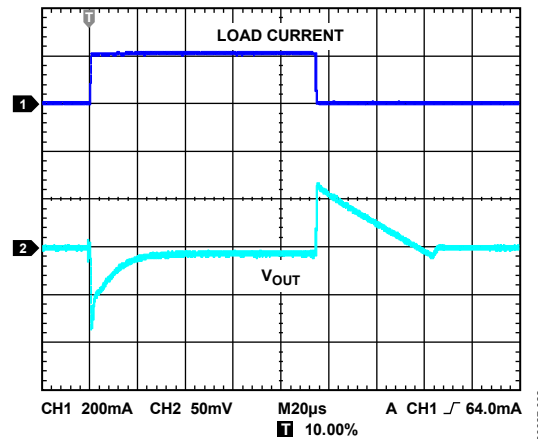


Figure 24. Load Transient Response, $C_{IN}, C_{OUT} = 1\mu F$, $I_{LOAD} = 1mA$ to $200mA$

08627-022

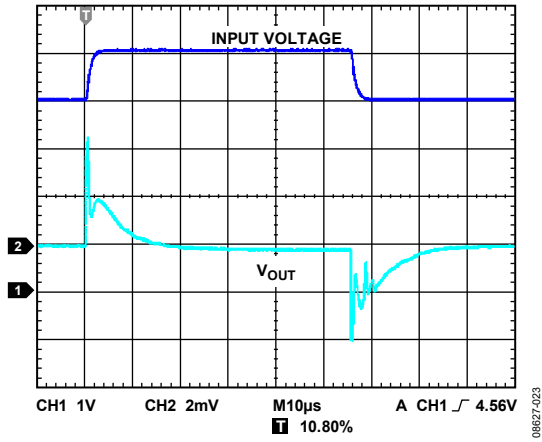


Figure 25. Line Transient Response, $C_{IN}, C_{OUT} = 1 \mu F, I_{LOAD} = 200 \text{ mA}$

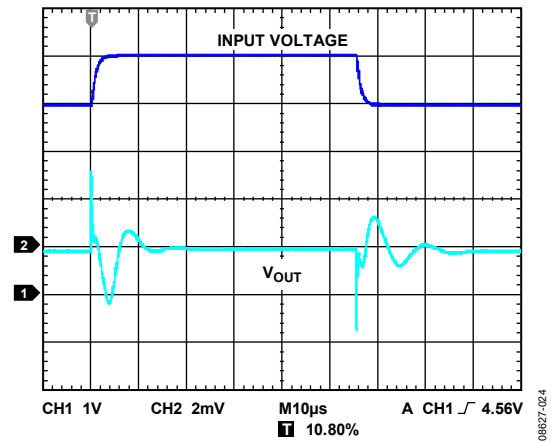


Figure 26. Line Transient Response, $C_{IN}, C_{OUT} = 1 \mu F, I_{LOAD} = 1 \text{ mA}$

THEORY OF OPERATION

The ADP151 is an ultralow noise, low quiescent current, LDO linear regulator that operates from 2.2 V to 5.5 V and can provide up to 200 mA of output current. Drawing a low 265 μA of operating supply current (typical) at full load makes the ADP151 ideal for battery operated, portable equipment. Shutdown current consumption is typically 0.2 μA .

Using a proprietary architecture, the ADP151 provides superior noise performance for noise sensitive analog and RF applications without the need for a noise bypass capacitor. The ADP151 is also optimized for use with small 1 μF ceramic capacitors.

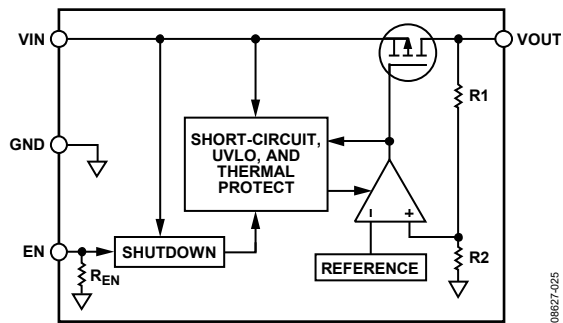


Figure 27. Internal Block Diagram

Internally, the ADP151 consists of a reference, an error amplifier, a feedback voltage divider, and a PMOS pass transistor. Output current is delivered via the PMOS pass device, which is controlled by the error amplifier. The error amplifier compares the reference voltage with the feedback voltage from the output and amplifies the difference. If the feedback voltage is lower than the reference voltage, the gate of the PMOS device pulls lower, allowing more current to pass and increasing the output voltage. If the feedback voltage is higher than the reference voltage, the gate of the PMOS device pulls higher, allowing less current to pass and decreasing the output voltage.

An internal pull-down resistor on the EN input holds the input low when the pin is left open.

The ADP151 is available in 16 output voltage options, ranging from 1.1 V to 3.3 V. The ADP151 uses the EN pin to enable and disable the VOUT pin under normal operating conditions. When EN is high, VOUT turns on, and when EN is low, VOUT turns off. For automatic startup, tie EN to VIN.

APPLICATIONS INFORMATION

CAPACITOR SELECTION

Output Capacitor

The ADP151 is designed for operation with small, space-saving ceramic capacitors but can function with most commonly used capacitors as long as care is taken with regard to the effective series resistance (ESR) value. The ESR of the output capacitor affects the stability of the LDO control loop. A minimum of 1 μF capacitance with an ESR of 1 Ω or less is recommended to ensure the stability of the ADP151. Transient response to changes in load current is also affected by output capacitance. Using a larger value of output capacitance improves the transient response of the ADP151 to large changes in load current. Figure 28 shows the transient responses for an output capacitance value of 1 μF .

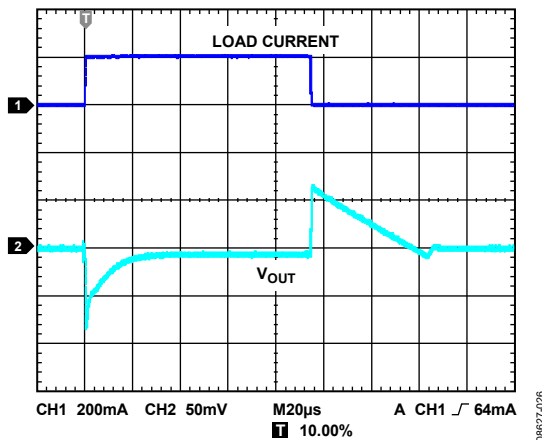


Figure 28. Output Transient Response, $C_{OUT} = 1 \mu\text{F}$

Input Bypass Capacitor

Connecting a 1 μF capacitor from VIN to GND reduces the circuit sensitivity to the PCB layout, especially when long input traces or high source impedance are encountered. If greater than 1 μF of output capacitance is required, the input capacitor must be increased to match it.

Input and Output Capacitor Properties

Any good quality ceramic capacitor can be used with the ADP151 as long as the capacitor meets the minimum capacitance and maximum ESR requirements. Ceramic capacitors are manufactured with a variety of dielectrics, each with different behavior over temperature and applied voltage. Capacitors must have an adequate dielectric to ensure the minimum capacitance over the necessary temperature range and dc bias conditions. X5R or X7R dielectrics with a voltage rating of 6.3 V or 10 V are recommended. Y5V and Z5U dielectrics are not recommended due to their poor temperature and dc bias characteristics.

Figure 29 depicts the capacitance vs. voltage bias characteristic of an 0402, 1 μF , 10 V X5R capacitor. The voltage stability of a capacitor is strongly influenced by the capacitor size and voltage rating. In general, a capacitor in a larger package or higher voltage rating exhibits better stability. The temperature variation of the X5R dielectric is $\sim\pm 15\%$ over the -40°C to $+85^\circ\text{C}$ temperature range and is not a function of package or voltage rating.

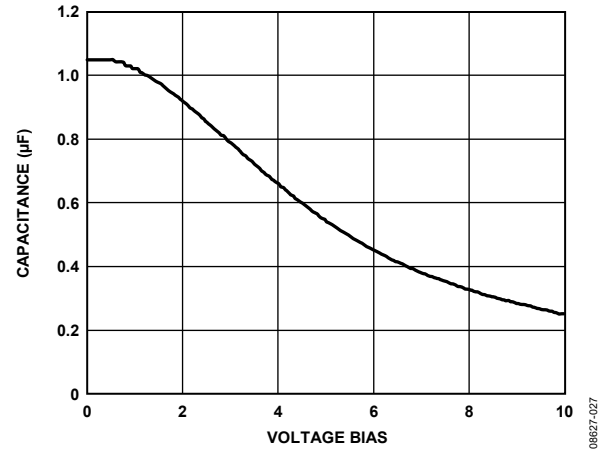


Figure 29. Capacitance vs. Voltage Bias Characteristic

Use Equation 1 to determine the worst case capacitance, accounting for capacitor variation over temperature, component tolerance, and voltage.

$$C_{EFF} = C_{BIAS} \times (1 - TEMPCO) \times (1 - TOL) \quad (1)$$

where:

C_{BIAS} is the effective capacitance at the operating voltage.
 $TEMPCO$ is the worst-case capacitor temperature coefficient.
 TOL is the worst-case component tolerance.

In this example, the worst-case temperature coefficient ($TEMPCO$) over -40°C to $+85^\circ\text{C}$ is 15% for an X5R dielectric, the tolerance of the capacitor (TOL) is 10%, and C_{BIAS} is 0.94 μF at 1.8 V, as shown in Figure 29.

Substituting these values in Equation 1 yields the following:

$$C_{EFF} = 0.94 \mu\text{F} \times (1 - 0.15) \times (1 - 0.1) = 0.719 \mu\text{F}$$

Therefore, the capacitor chosen in this example meets the minimum capacitance requirement of the LDO over temperature and tolerance at the chosen output voltage.

To guarantee the performance of the ADP151, it is imperative that the effects of dc bias, temperature, and tolerances on the behavior of the capacitors be evaluated for each application.

ENABLE FEATURE

The ADP151 uses the EN pin to enable and disable the VOUT pin under normal operating conditions. As shown in Figure 30, when a rising voltage on EN crosses the active threshold, VOUT turns on. When a falling voltage on EN crosses the inactive threshold, VOUT turns off.

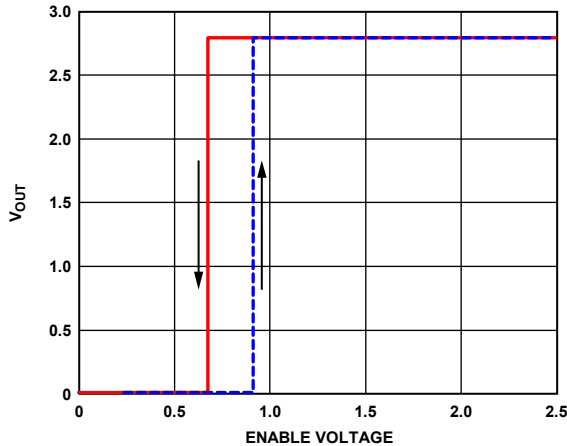


Figure 30. ADP151 Typical EN Pin Operation

As shown in Figure 30, the EN pin has hysteresis built in to prevent on and off oscillations that can occur due to noise on the EN pin as this pin passes through the threshold points.

The EN pin active and inactive thresholds are derived from the VIN voltage. Therefore, these thresholds vary with changing input voltage. Figure 31 shows typical EN active and inactive thresholds when the input voltage varies from 2.2 V to 5.5 V.

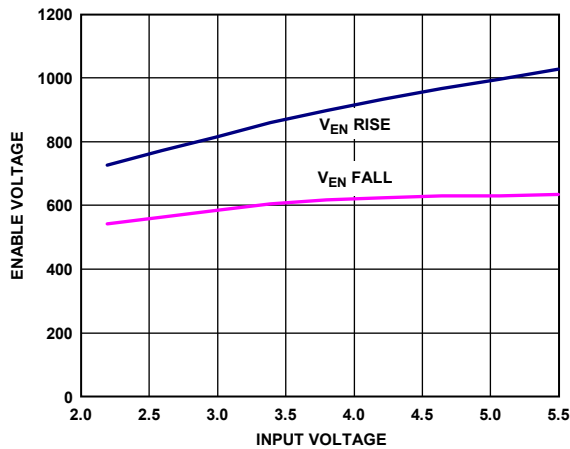


Figure 31. Typical EN Pin Thresholds vs. Input Voltage

The ADP151 uses an internal soft start to limit the inrush current when the output is enabled. The start-up time for the 3.3 V option is approximately 160 μs from the time the EN active threshold is crossed to when the output reaches 90% of its final value. As shown in Figure 32, the start-up time is dependent on the output voltage setting.

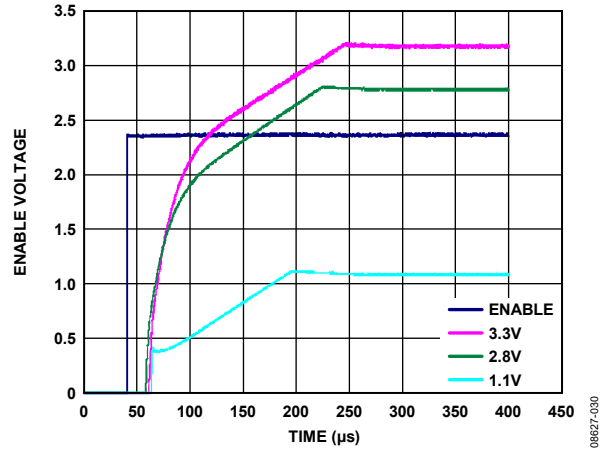


Figure 32. Typical Start-Up Behavior

ADJUSTABLE OUTPUT VOLTAGE OPERATION

The unique architecture of the ADP151 makes an adjustable version difficult to implement in silicon. However, it is possible to create an adjustable regulator at the expense of increasing the quiescent current of the regulator circuit.

The ADP151, and similar LDOs, are designed to regulate the output voltage (VOUT) appearing at the VOUT pin with respect to the GND pin. If the GND pin is at a potential other than 0 V (for example, at the offset voltage (VOFFSET)), the ADP151 output voltage is VOUT + VOFFSET. By taking advantage of this behavior, it is possible to create an adjustable ADP151 circuit that retains most of the desirable characteristics of the ADP151.

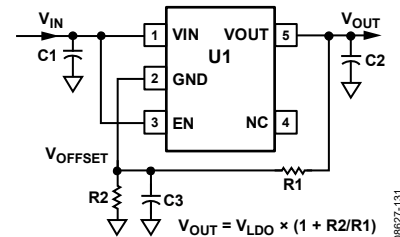


Figure 33. Adjustable LDO Using the ADP151

The circuit shown in Figure 33 is an example of an adjustable LDO using the ADP151. A stable VOFFSET voltage is created by passing a known current through R2. The current through R2 is determined by the voltage across R1. Because the voltage across R1 is set by the voltage between VOUT and GND, the current passing through R2 is fixed, and VOFFSET is stable.

To minimize the effect variation of the ADP151 ground current (IGND) with load, it is best to keep R1 as small as possible. It is also best to size the current passing through R2 to at least 20× greater than the maximum expected ground current.

To create a 4 V LDO circuit, start with the 3.3 V version of the ADP151 to minimize the value of R2. Because V_{OUT} is 4 V, V_{OFFSET} must be 0.7 V, and the current through R2 must be 7 mA. R1 is, therefore, 3.3 V/7 mA or 471 Ω . A 470 Ω standard value introduces less than 1% error. Capacitor C3 is necessary to stabilize the LDO. A value of 1 μ F is adequate.

Figure 34 through Figure 38 show the typical performance of the 4 V LDO circuit.

The noise performance of the 4 V LDO circuit is only about 1 μ V worse than the same LDO used at 3.3 V because the output noise of the circuit is almost solely determined by the LDO and not the external components. The small difference may be attributed to the internally generated noise in the LDO ground current working with R2. By keeping R2 small, this noise contribution can be minimized.

The PSRR of the 4 V circuit is as much as 10 dB poorer than the 3.3 V LDO with 500 mV of headroom because the ground current of the LDO varies slightly with input voltage. This, in turn, modulates V_{OFFSET} and reduces the PSRR of the regulator. By increasing the headroom to 1 V, the PSRR performance is nearly restored to the performance of the fixed output LDO.

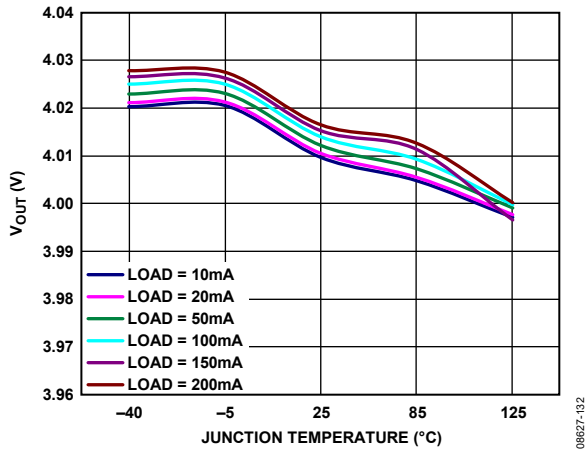


Figure 34. 4 V LDO Circuit, Typical Load Regulation over Temperature

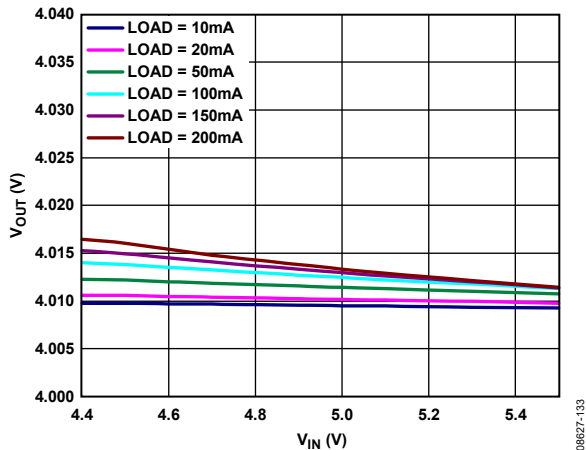


Figure 35. 4 V LDO Circuit, Typical Line Regulation over Load Current

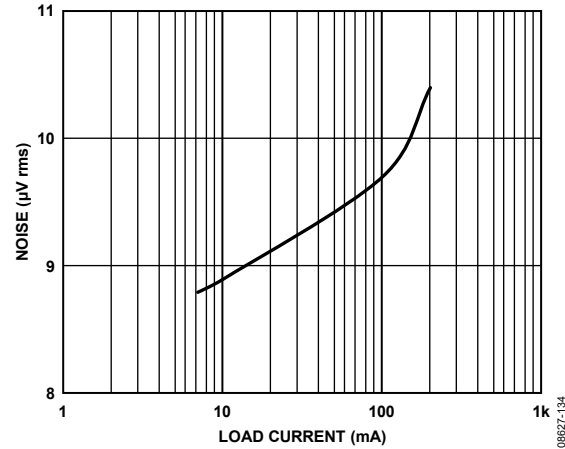


Figure 36. 4 V LDO Circuit, Typical RMS Output Noise, 10 Hz to 100 kHz

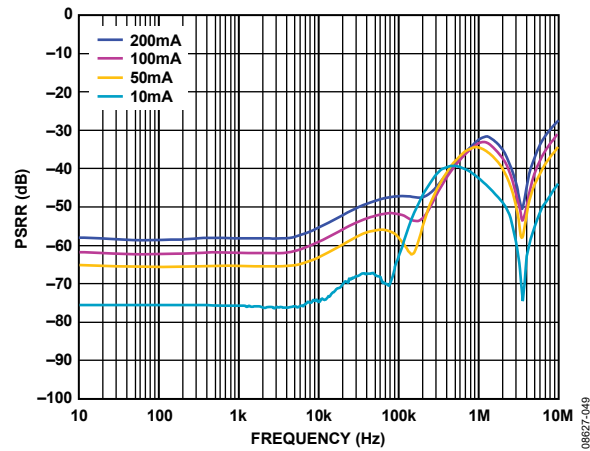


Figure 37. 4 V LDO Circuit, Typical PSRR vs. Load Current, 1 V Headroom

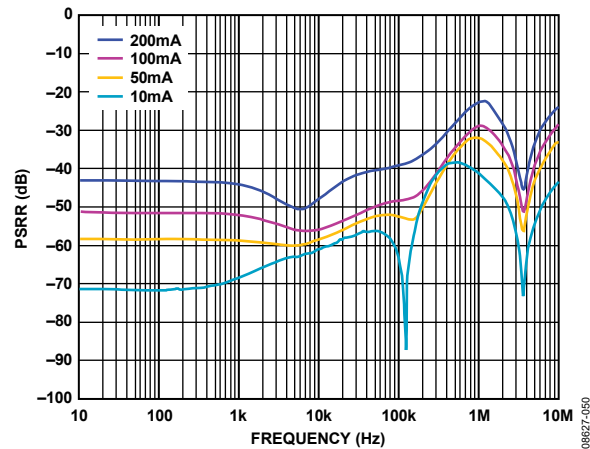


Figure 38. 4 V LDO Circuit, Typical PSRR vs. Load Current, 500 mV Headroom

CURRENT-LIMIT AND THERMAL OVERLOAD PROTECTION

The ADP151 is protected against damage due to excessive power dissipation by current and thermal overload protection circuits. The ADP151 is designed to current limit when the output load reaches 300 mA (typical). When the output load exceeds 300 mA, the output voltage is reduced to maintain a constant current limit.

Thermal overload protection is included, which limits the junction temperature to a maximum of 150°C (typical). Under extreme conditions (that is, high ambient temperature and power dissipation) when the junction temperature starts to rise above 150°C, the output is turned off, reducing the output current to 0. When the junction temperature drops below 135°C, the output is turned on again, and the output current is restored to its nominal value.

Consider the case where a hard short from VOUT to ground occurs. At first, the ADP151 current limits, so that only 300 mA is conducted into the short. If self heating of the junction causes its temperature to rise above 150°C, thermal shutdown activates, turning off the output and reducing the output current to 0. As the junction temperature cools and drops below 135°C, the output turns on and conducts 300 mA into the short, again causing the junction temperature to rise above 150°C. This thermal oscillation between 135°C and 150°C causes a current oscillation between 300 mA and 0 mA that continues as long as the short remains at the output.

Current-limit and thermal limit protections protect the device against accidental overload conditions. For reliable operation, device power dissipation must be externally limited so that junction temperatures do not exceed 125°C.

THERMAL CONSIDERATIONS

In most applications, the ADP151 does not dissipate much heat due to its high efficiency. However, in applications with a high ambient temperature and a high supply voltage to output voltage differential, the heat dissipated in the package can cause the junction temperature of the die to exceed the maximum junction temperature of 125°C.

When the junction temperature exceeds 150°C, the converter enters thermal shutdown. The converter recovers only after the junction temperature has decreased below 135°C to prevent any permanent damage. Therefore, thermal analysis for the chosen application is important to guarantee reliable performance over all conditions. The junction temperature of the die is the sum of the ambient temperature of the environment and the temperature rise of the package due to the power dissipation, as shown in Equation 2.

To guarantee reliable operation, the junction temperature of the ADP151 must not exceed 125°C. To ensure that the junction temperature stays below this maximum value, the user must be aware of the parameters that contribute to junction temperature changes. These parameters include ambient temperature, power dissipation in the power device, and thermal resistances between the junction and ambient air (θ_{JA}). The θ_{JA} number is dependent on the package assembly compounds that are used and the amount of copper used to solder the package GND pins to the PCB.

Table 6 shows typical θ_{JA} values of the 5-lead TSOT, the 6-lead LFCSP, and the 4-ball WLCSP for various PCB copper sizes. Table 7 shows the typical Ψ_{JB} values of the 5-lead TSOT, the 6-lead LFCSP, and the 4-ball WLCSP.

Table 6. Typical θ_{JA} Values

Copper Size (mm ²)	θ_{JA} (°C/W)		
	TSOT	WLCSP	LFCSP
0 ¹	170	260	231.2
50	152	159	161.8
100	146	157	150.1
300	134	153	111.5
500	131	151	91.8

¹ Device soldered to minimum size pin traces.

Table 7. Typical Ψ_{JB} Values

Model	Ψ_{JB} (°C/W)
5-Lead TSOT	43
4-Ball WLCSP	58
6-Lead LFCSP	28.3

To calculate the junction temperature of the ADP151, use the following equation:

$$T_J = T_A + (P_D \times \theta_{JA}) \quad (2)$$

where:

T_A is the ambient temperature.

P_D is the power dissipation in the die, given by

$$P_D = ((V_{IN} - V_{OUT}) \times I_{LOAD}) + (V_{IN} \times I_{GND}) \quad (3)$$

where:

V_{IN} and V_{OUT} are input and output voltages, respectively.

I_{LOAD} is the load current.

I_{GND} is the ground current.

Power dissipation due to ground current is small and can be ignored. Therefore, the junction temperature equation simplifies to the following:

$$T_J = T_A + (((V_{IN} - V_{OUT}) \times I_{LOAD}) \times \theta_{JA}) \quad (4)$$

As shown in Equation 4, for a given ambient temperature, input to output voltage differential, and continuous load current, there exists a minimum copper size requirement for the PCB to ensure that the junction temperature does not rise above 125°C.

Figure 39 through Figure 59 show junction temperature calculations for various ambient temperatures, load currents, V_{IN} to V_{OUT} differentials, and areas of PCB copper.

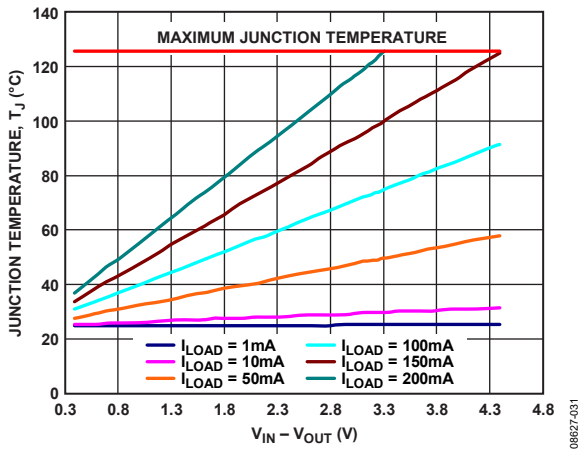


Figure 39. WLCSP 500 mm² of PCB Copper, $T_A = 25^\circ\text{C}$

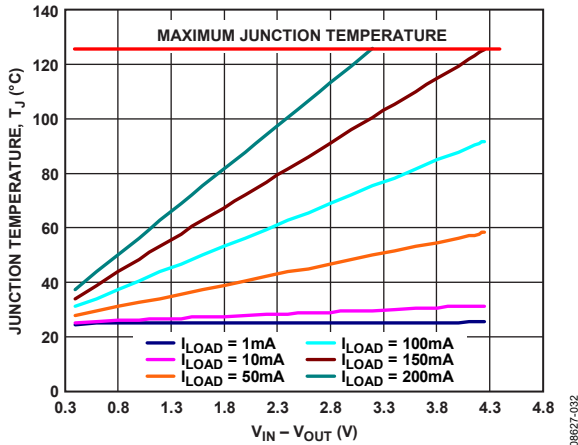


Figure 40. WLCSP 100 mm² of PCB Copper, $T_A = 25^\circ\text{C}$

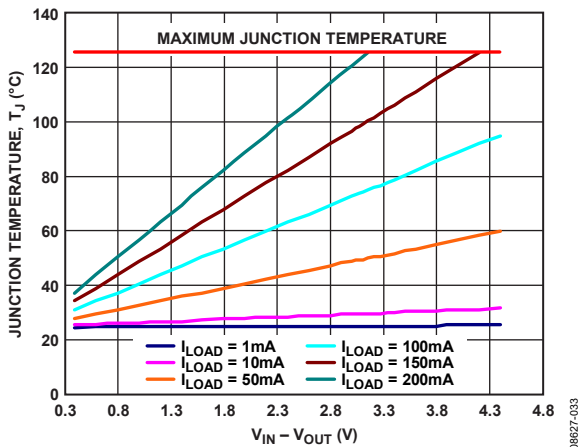


Figure 41. WLCSP 50 mm² of PCB Copper, $T_A = 25^\circ\text{C}$

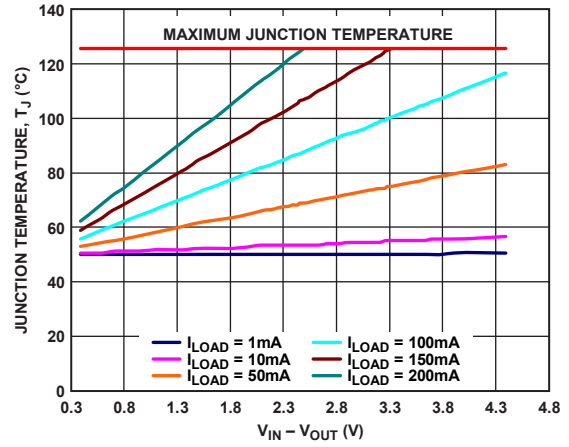


Figure 42. WLCSP 500 mm² of PCB Copper, $T_A = 50^\circ\text{C}$

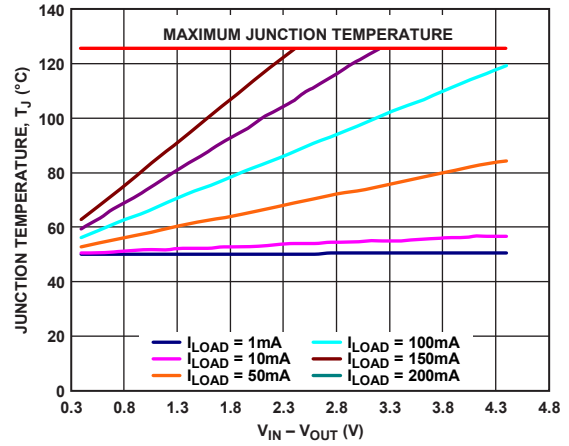


Figure 43. WLCSP 100 mm² of PCB Copper, $T_A = 50^\circ\text{C}$

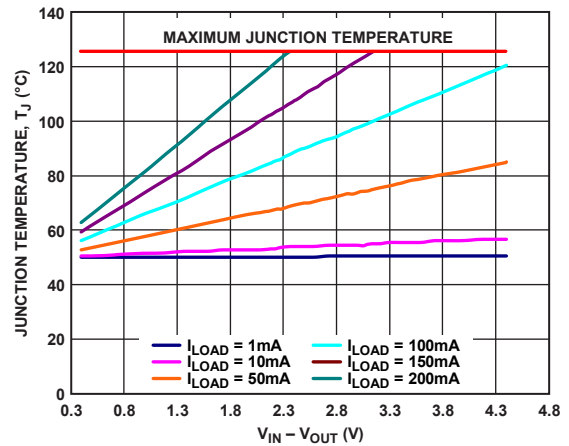


Figure 44. WLCSP 50 mm² of PCB Copper, $T_A = 50^\circ\text{C}$

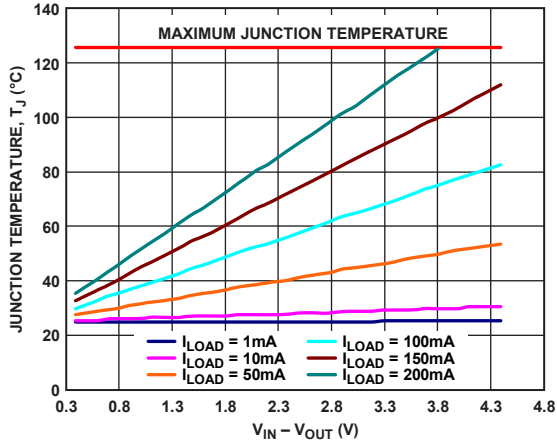


Figure 45. TSOT 500 mm² of PCB Copper, T_A = 25°C

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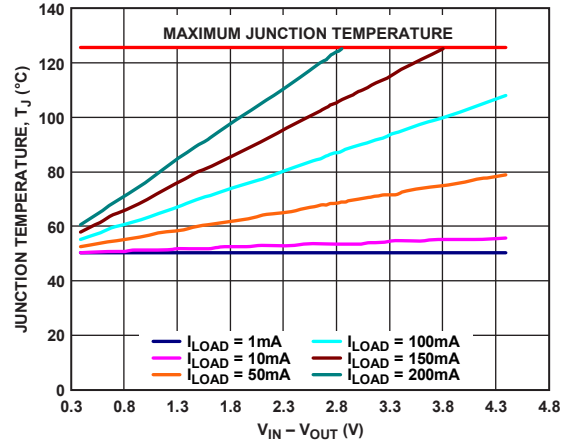


Figure 48. TSOT 500 mm² of PCB Copper, T_A = 50°C

08627-040

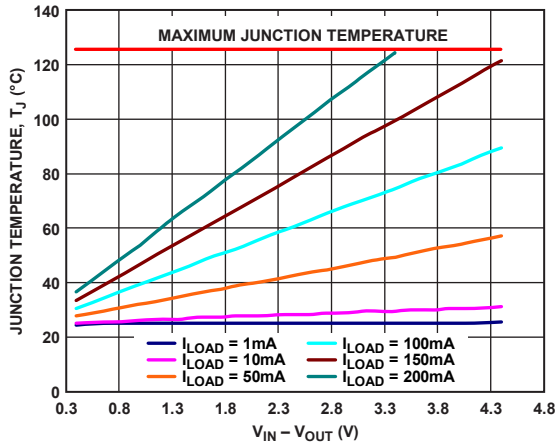


Figure 46. TSOT 100 mm² of PCB Copper, T_A = 25°C

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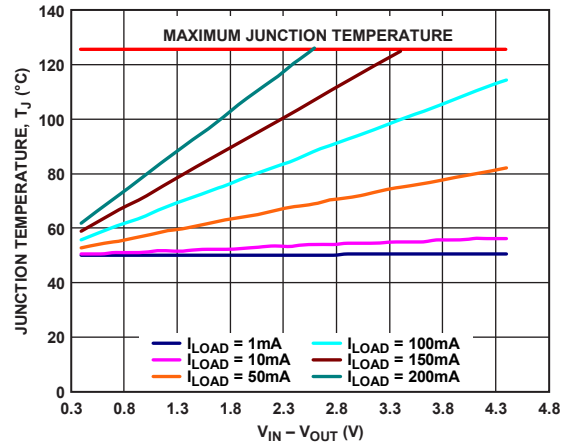


Figure 49. TSOT 100 mm² of PCB Copper, T_A = 50°C

08627-041

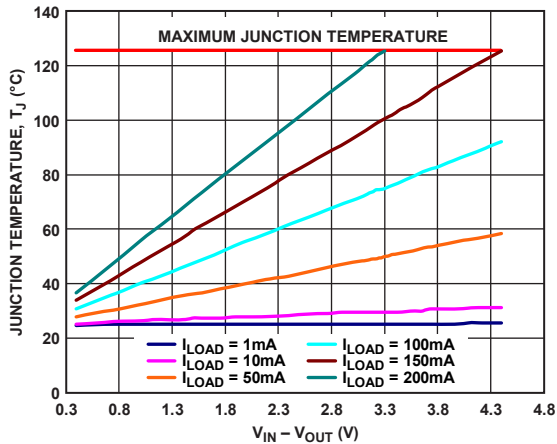


Figure 47. TSOT 50 mm² of PCB Copper, T_A = 25°C

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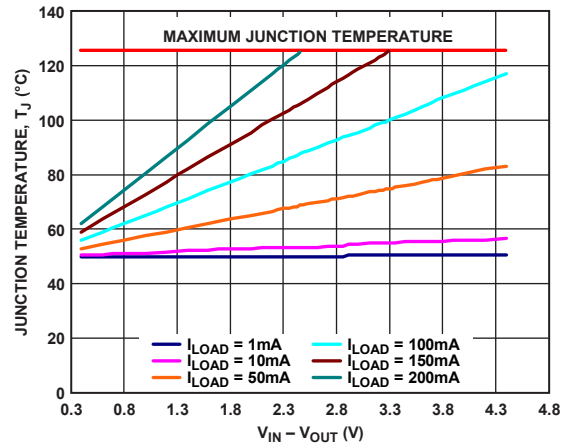


Figure 50. TSOT 50 mm² of PCB Copper, T_A = 50°C

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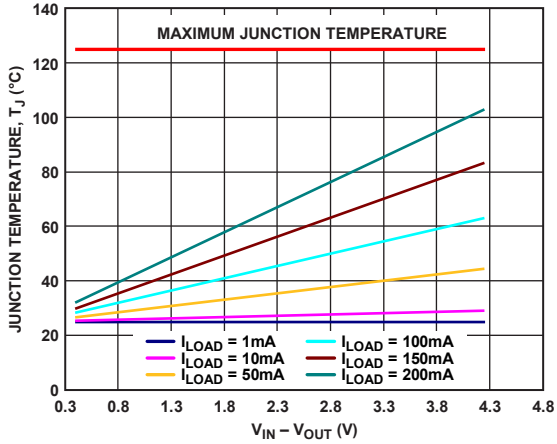


Figure 51. LFCSP 500 mm² of PCB Copper, T_A = 25°C

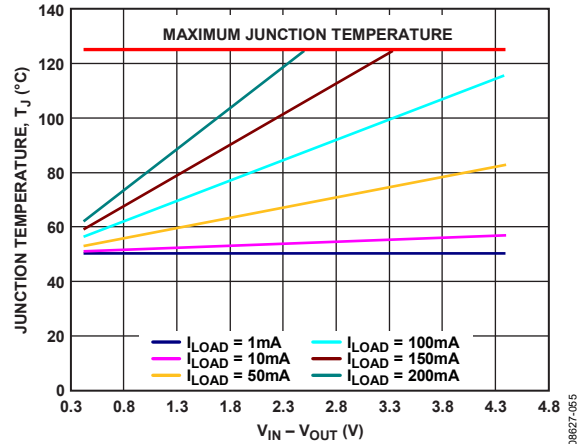


Figure 54. LFCSP 500 mm² of PCB Copper, T_A = 50°C

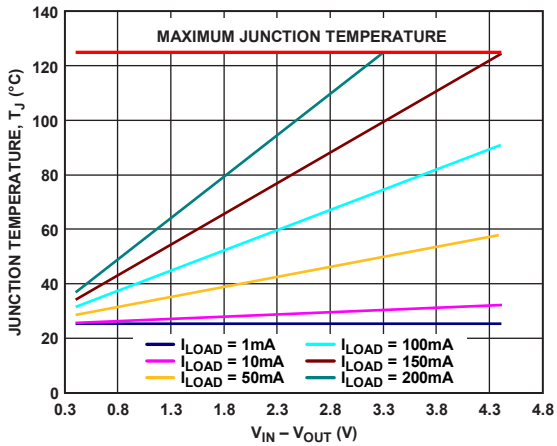


Figure 52. LFCSP 100 mm² of PCB Copper, T_A = 25°C

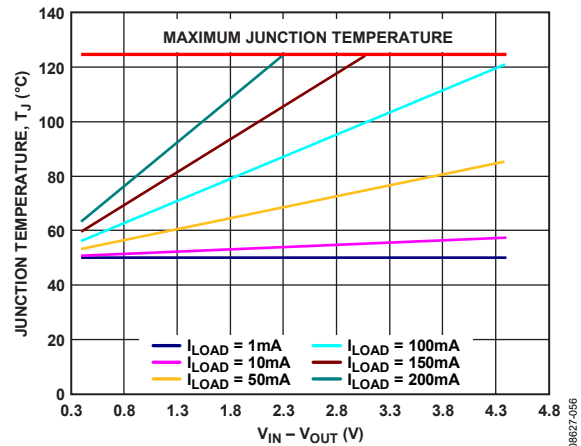


Figure 55. LFCSP 100 mm² of PCB Copper, T_A = 50°C

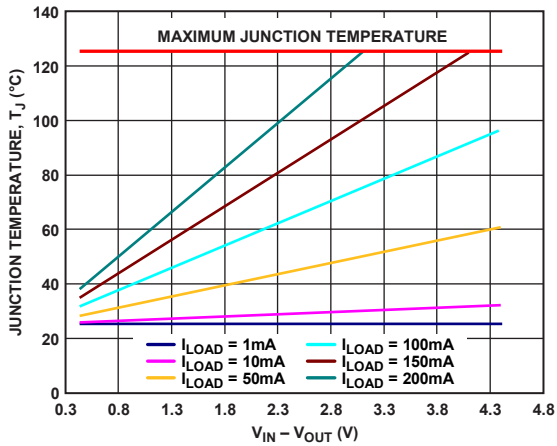


Figure 53. LFCSP 50 mm² of PCB Copper, T_A = 25°C

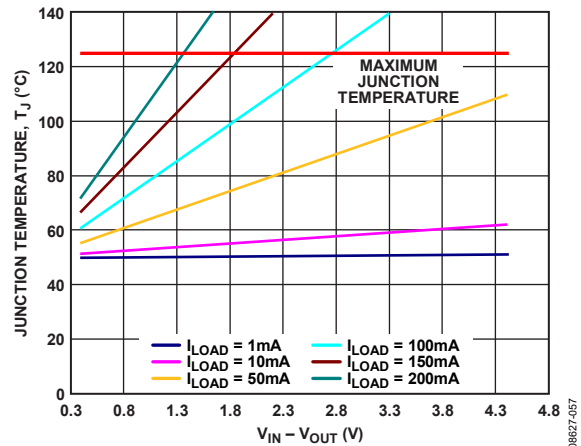


Figure 56. LFCSP 50 mm² of PCB Copper, T_A = 50°C

In the case where the board temperature is known, use the thermal characterization parameter (Ψ_{JB}) to estimate the junction temperature rise (see Figure 57 and Figure 58). Maximum T_j is calculated from the T_B and P_D using the following formula:

$$T_j = T_B + (P_D \times \Psi_{JB}) \tag{5}$$

The typical value of Ψ_{JB} is 58°C/W for the 4-ball WLCSP, 43°C/W for the 5-lead TSOT, and 28.3°C/W for the 6-lead LFCSP.

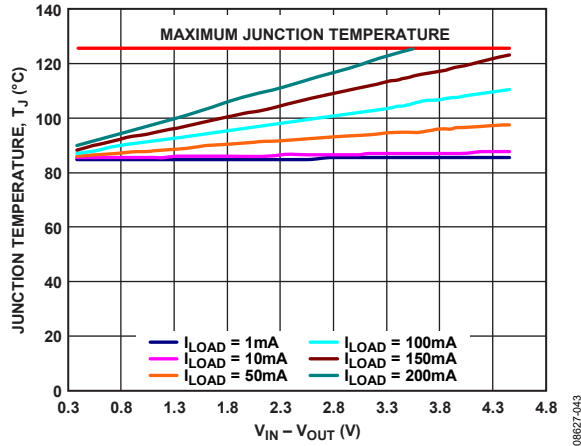


Figure 57. WLCSP, $T_A = 85^\circ\text{C}$

08627-043

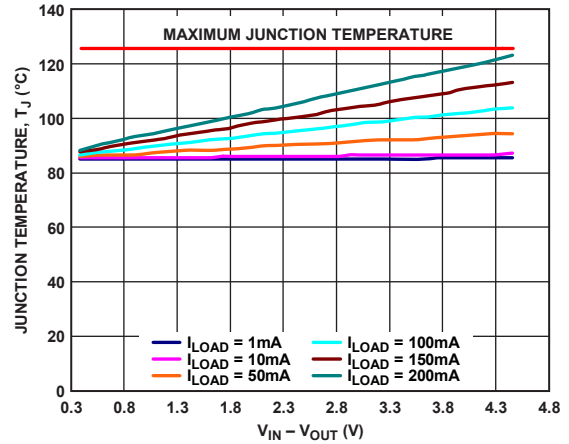


Figure 58. TSOT, $T_A = 85^\circ\text{C}$

08627-044

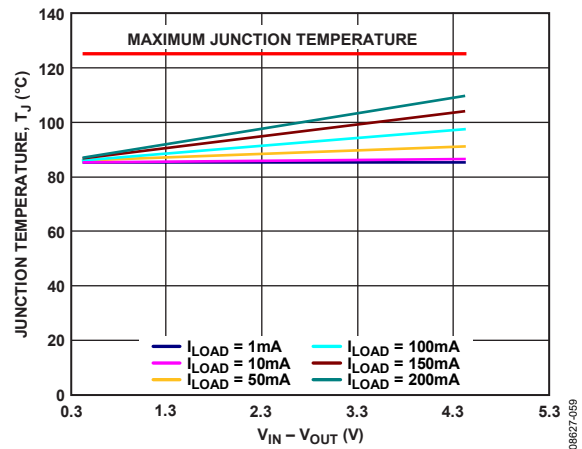


Figure 59. LFCSP, $T_A = 85^\circ\text{C}$

08627-056

PRINTED CIRCUIT BOARD LAYOUT CONSIDERATIONS

Heat dissipation from the package can be improved by increasing the amount of copper attached to the pins of the ADP151. However, as listed in Table 6, a point of diminishing returns is eventually reached beyond which an increase in the copper size does not yield significant heat dissipation benefits.

Place the input capacitor as close as possible to the VIN and the GND pins. Place the output capacitor as close as possible to the VOUT and the GND pins. Use of 0402 or 0603 size capacitors achieves the smallest possible footprint solution on boards where area is limited.

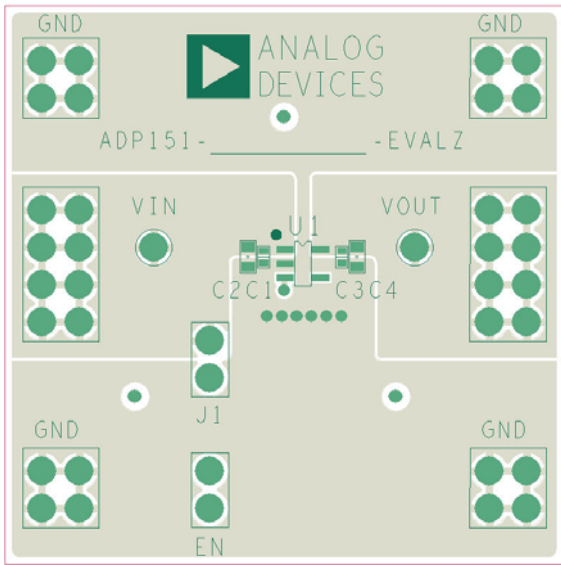


Figure 60. Example TSOT PCB Layout

08827-045

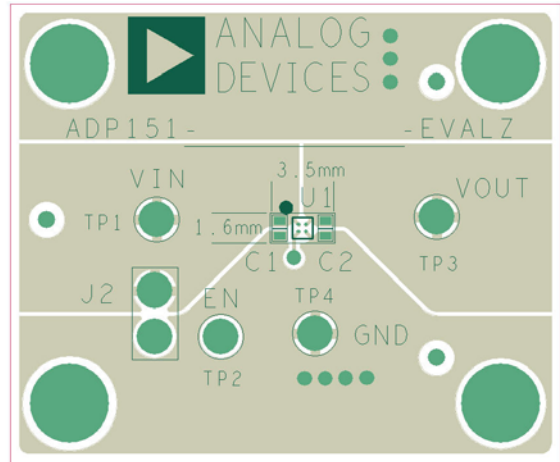


Figure 61. Example WLCSP PCB Layout

08827-046

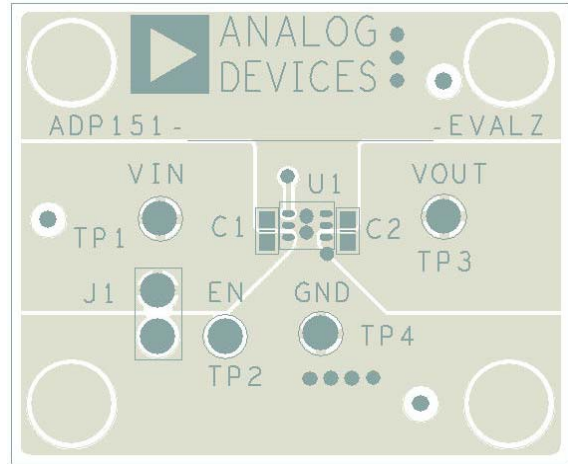


Figure 62. Example LFCSP PCB Layout

08827-054

OUTLINE DIMENSIONS

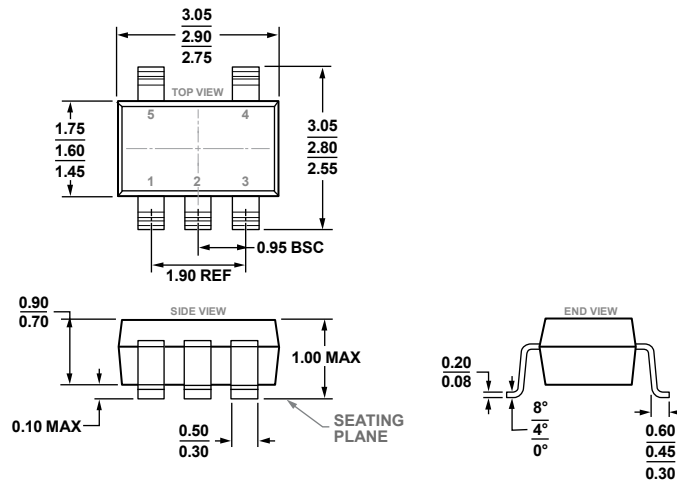


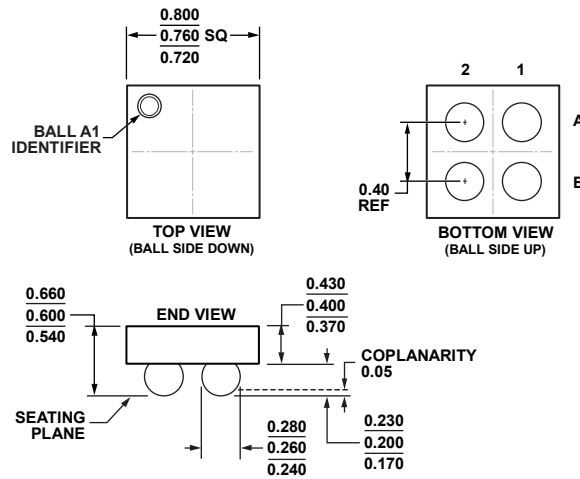
FIG-010003

04-05-2017-B

COMPLIANT TO JEDEC STANDARDS MO-193-AB

Figure 63. 5-Lead Thin Small Outline Transistor Package [TSOT] (UJ-5)

Dimensions show in millimeters



04-16-2012-A

Figure 64. 4-Ball Wafer Level Chip Scale Package [WL CSP] (CB-4-3)

Dimensions show in millimeters

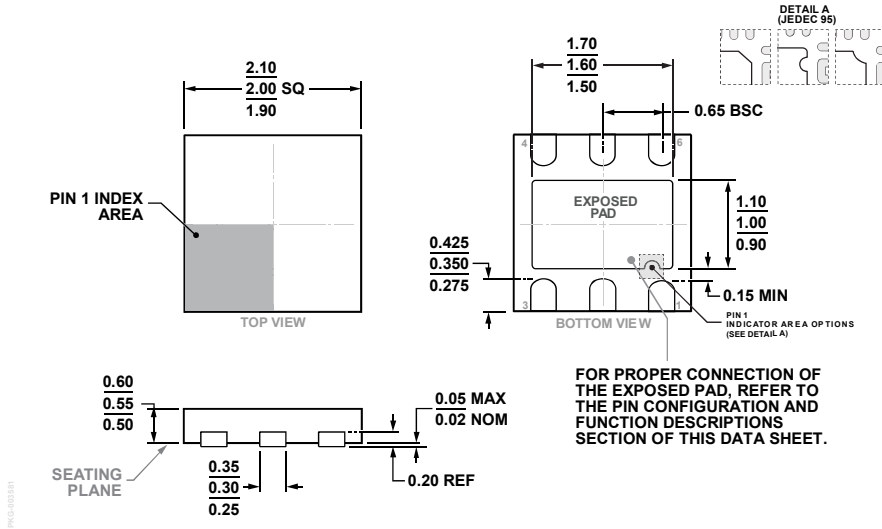


Figure 65. 6-Lead Lead Frame Chip Scale Package [LFCSP], 2.00 mm x 2.00 mm Body and 0.55 mm Package Height (CP-6-3)
Dimensions show in millimeters

ORDERING GUIDE

Model ^{1,2}	Temperature Range	Output Voltage (V) ³	Package Description	Package Option ⁴	Marking Code
ADP151ACBZ-1.1-R7	-40°C to +125°C	1.1	4-Ball WLCSP	CB-4-3	8R
ADP151ACBZ-1.2-R7	-40°C to +125°C	1.2	4-Ball WLCSP	CB-4-3	4R
ADP151ACBZ-1.5-R7	-40°C to +125°C	1.5	4-Ball WLCSP	CB-4-3	4S
ADP151ACBZ-1.8-R7	-40°C to +125°C	1.8	4-Ball WLCSP	CB-4-3	4T
ADP151ACBZ-2.1-R7	-40°C to +125°C	2.1	4-Ball WLCSP	CB-4-3	5E
ADP151ACBZ-2.5-R7	-40°C to +125°C	2.5	4-Ball WLCSP	CB-4-3	4U
ADP151ACBZ-2.6-R7	-40°C to +125°C	2.6	4-Ball WLCSP	CB-4-3	8Q
ADP151ACBZ-2.75-R7	-40°C to +125°C	2.75	4-Ball WLCSP	CB-4-3	4V
ADP151ACBZ-2.8-R7	-40°C to +125°C	2.8	4-Ball WLCSP	CB-4-3	4X
ADP151ACBZ-2.85-R7	-40°C to +125°C	2.85	4-Ball WLCSP	CB-4-3	4Y
ADP151ACBZ-3.0-R7	-40°C to +125°C	3.0	4-Ball WLCSP	CB-4-3	4Z
ADP151ACBZ-3.3-R7	-40°C to +125°C	3.3	4-Ball WLCSP	CB-4-3	50
ADP151WACBZ-1.1-R7	-40°C to +125°C	1.1	4-Ball WLCSP	CB-4-3	F4
ADP151WACBZ-1.2-R7	-40°C to +125°C	1.2	4-Ball WLCSP	CB-4-3	F5
ADP151WACBZ-1.5-R7	-40°C to +125°C	1.5	4-Ball WLCSP	CB-4-3	F6
ADP151WACBZ-1.8-R7	-40°C to +125°C	1.8	4-Ball WLCSP	CB-4-3	EW
ADP151WACBZ-2.1-R7	-40°C to +125°C	2.1	4-Ball WLCSP	CB-4-3	F7
ADP151WACBZ-2.5-R7	-40°C to +125°C	2.5	4-Ball WLCSP	CB-4-3	F8
ADP151WACBZ-2.6-R7	-40°C to +125°C	2.6	4-Ball WLCSP	CB-4-3	F9
ADP151WACBZ-2.75-R7	-40°C to +125°C	2.75	4-Ball WLCSP	CB-4-3	FA
ADP151WACBZ-2.8-R7	-40°C to +125°C	2.8	4-Ball WLCSP	CB-4-3	FB
ADP151WACBZ-2.85-R7	-40°C to +125°C	2.85	4-Ball WLCSP	CB-4-3	FC
ADP151WACBZ-3.0-R7	-40°C to +125°C	3.0	4-Ball WLCSP	CB-4-3	FD
ADP151WACBZ-3.3-R7	-40°C to +125°C	3.3	4-Ball WLCSP	CB-4-3	FE

Model ^{1,2}	Temperature Range	Output Voltage (V) ³	Package Description	Package Option ⁴	Marking Code
ADP151AUJZ-1.2-R7	-40°C to +125°C	1.2	5-Lead TSOT	UJ-5	LF6
ADP151AUJZ-1.5-R7	-40°C to +125°C	1.5	5-Lead TSOT	UJ-5	LF7
ADP151AUJZ-1.8-R7	-40°C to +125°C	1.8	5-Lead TSOT	UJ-5	LF8
ADP151AUJZ-2.5-R7	-40°C to +125°C	2.5	5-Lead TSOT	UJ-5	LF9
ADP151AUJZ-2.8-R7	-40°C to +125°C	2.8	5-Lead TSOT	UJ-5	LFG
ADP151AUJZ-2.9-R7	-40°C to +125°C	2.9	5-Lead TSOT	UJ-5	LTL
ADP151AUJZ-3.0-R7	-40°C to +125°C	3.0	5-Lead TSOT	UJ-5	LFH
ADP151AUJZ-3.3-R7	-40°C to +125°C	3.3	5-Lead TSOT	UJ-5	LFJ
ADP151WAUJZ-1.8-R7	-40°C to +125°C	1.8	5-Lead TSOT	UJ-5	LVP
ADP151ACPZ-1.2-R7	-40°C to +125°C	1.2	6-Lead LFCSP	CP-6-3	LF6
ADP151ACPZ-1.5-R7	-40°C to +125°C	1.5	6-Lead LFCSP	CP-6-3	LF7
ADP151ACPZ-1.8-R7	-40°C to +125°C	1.8	6-Lead LFCSP	CP-6-3	LF8
ADP151ACPZ-2.5-R7	-40°C to +125°C	2.5	6-Lead LFCSP	CP-6-3	LF9
ADP151ACPZ-2.7-R7	-40°C to +125°C	2.7	6-Lead LFCSP	CP-6-3	LKZ
ADP151ACPZ-2.8-R7	-40°C to +125°C	2.8	6-Lead LFCSP	CP-6-3	LFG
ADP151ACPZ-3.0-R7	-40°C to +125°C	3.0	6-Lead LFCSP	CP-6-3	LFH
ADP151ACPZ-3.3-R7	-40°C to +125°C	3.3	6-Lead LFCSP	CP-6-3	LFJ
ADP151UJZ-REDYKIT			TSOT Evaluation Board Kit		
ADP151CPZ-REDYKIT			LFCSP Evaluation Board Kit		
ADP151CB-3.3-EVALZ			Evaluation Board		

¹ Z = RoHS Compliant Part.

² W = Qualified for Automotive Applications.

³ For additional voltage options for the ADP151ACBZ package option, contact a local Analog Devices, Inc., sales or distribution representative.

⁴ The ADP151ACBZ package option is halide free.

AUTOMOTIVE PRODUCTS

The ADP151W models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.